# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules 36–75Vdc Input; 12.0Vdc Output; 10A Output Current



### **Applications**

- Distributed Power Architectures
- Wireless Networks
- Access and Optical Network Equipment
- Enterprise Networks including Power over Ethernet (PoE)

### **Options**

- Negative Remote On/Off logic
- Over current/Over temperature/Over voltage protections (Auto-restart)
- Heat plate versions (-H)
- Surface Mount version (-S)

#### **Features**

- Compliant to RoHS EU Directive 2011/65/EU and amended Directive (EU) 2015/863. (Z versions)
- Compliant to REACH Directive (EC) No 1907/2006
- Compatible in a Pb-free or SnPb reflow environment
- High efficiency 93.5% at 12V full load
- Industry standard, DOSA compliant, Eighth brick footprint

57.9mm x 22.9mm x 7.8mm (2.28in x 0.90in x 0.31in)

- Wide Input voltage range: 36-75 Vdc
- Tightly regulated output
- Constant switching frequency
- Positive Remote On/Off logic
- Input under/over voltage protection
- Output overcurrent/voltage protection
- Over-temperature protection
- Remote sense
- No minimum load required
- No reverse current during output shutdown
- Output Voltage adjust: 80% to 110% of V<sub>o,nom</sub>
- Operating temperature range (-40°C to 85°C)
- ANSI/UL\* 62368-1 and CAN/CSA† C22.2 No. 62368-1 Recognized, DIN VDE‡ 0868-1/A11:2017 (EN62368-1:2014/A11:2017)
- CE mark meets 2014/35/EU directive§
- Meets the voltage and current requirements for ETSI 300-132-2 and complies with and licensed for Basic insulation
- 2250 Vdc Isolation tested in compliance with IEEE 802.3<sup>nt</sup> PoE standards
- ISO\*\*9001 and ISO 14001 certified manufacturing facilities

### **Description**

The EVW010A0B, Eighth-brick low-height power module is an isolated dc-dc converters that can deliver up to 10A of output current and provide a precisely regulated output voltage of 12V over a wide range of input voltages ( $V_{IN} = 36 - 75$ Vdc). The modules achieve typical full load efficiency of 93.5%. The open frame modules construction, available in both surface-mount and through-hole packaging, enable designers to develop cost and space efficient solutions. Standard features include remote On/Off, remote sense, output voltage adjustment, overvoltage, overcurrent and overtemperature protection.



### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

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### **Absolute Maximum Ratings**

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only, functional operation of the device is not implied at these or any other conditions in excess of those given in the operations sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect the device reliability.

Parameter	Device	Symbol	Min	Max	Unit
Input Voltage					
Continuous	All	$V_{IN}$	-0.3	80	$V_{dc}$
Transient (≤100 ms)	All	$V_{\text{IN,trans}}$	-0.3	100	$V_{dc}$
Operating Ambient Temperature	All	TA	-40	85	°C
(see Thermal Considerations section)					
Storage Temperature	All	$T_{stg}$	-55	125	°C
I/O Isolation voltage (100% factory Hi-Pot tested)	All	_	_	2250	$V_{dc}$

### **Electrical Specifications**

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions.

Parameter	Device	Symbol	Min	Тур	Max	Unit
Operating Input Voltage	All	V <sub>IN</sub>	36	48	75	$V_{dc}$
Maximum Input Current	All	I <sub>IN,max</sub>		3.4	3.7	A <sub>dc</sub>
(V <sub>IN</sub> = V <sub>IN, min</sub> to V <sub>IN, max</sub> , I <sub>O</sub> =I <sub>O, max</sub> )	All	IIN,max		3.4	3.7	Adc
Input No Load Current	All				75	mA
$(V_{IN} = V_{IN, nom}, I_0 = 0, module enabled)$	All	I <sub>IN,No</sub> load			75	IIIA
Input Stand-by Current						
$(V_{IN} = V_{IN, nom}, module disabled)$	All	I <sub>IN,stand-by</sub>			20	mA
Inrush Transient	All	I <sup>2</sup> t			0.5	A <sup>2</sup> s
Input Reflected Ripple Current, peak-to-peak (5Hz to 20MHz, $1\mu$ H source impedance; $V_{IN, min}$ to $V_{IN, max}$ , $I_{O}$ = $I_{Omax}$ ; See Test configuration section)	All			20		mA <sub>p-p</sub>
Input Ripple Rejection (120Hz)	All			50		dB

### CAUTION: This power module is not internally fused. An input line fuse must always be used.

This power module can be used in a wide variety of applications, ranging from simple standalone operation to an integrated part of sophisticated power architectures. To preserve maximum flexibility, internal fusing is not included, however, to achieve maximum safety and system protection, always use an input line fuse. The safety agencies require a time-delay fuse with a maximum rating of 8 A (see Safety Considerations section). Based on the information provided in this data sheet on inrush energy and maximum dc input current, the same type of fuse with a lower rating can be used. Refer to the fuse manufacturer's data sheet for further information.

# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36–75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Electrical Specifications** (continued)

Nominal Output Voltage Set-point   V <sub>NS</sub> -V <sub>N, min, lo=lo, max, Ta=25°C)                                    </sub>	Parameter	Device	Symbol	Min	Тур	Max	Unit
VN=VN, mol, lo=lo, max, Ta=25°C)         All         Vo         -3.0         -3.0         +3.0         % Vo, set           Output Voltage (Over all operating input voltage, resistive load, and temperature conditions until end of life)         All         -3.0         -3.0         -3.0         % Vo, set           Untine (Vne-VNs, min to Vol, max)         All         -         -         0.2         % Vo, set           Load (Io=lo, min to Io, max)         All         -         -         0.2         % Vo, set           Output Ripple and Noise on nominal output (Vne-VNs, com, Io=Io, max, Ta=Ta, min to Ta, max)         All         -         -         1.0         % Vo, set           Output Ripple and Allise on nominal output (Vne-VNs, com, Io=Io, max, Ta=Ta, min to Ta, max)         All         -         -         30         mV/ms           RMS (SHz to 20MHz bandwidth)         All         -         -         30         mV/ms           RMS (SHz to 20MHz bandwidth)         All         -         -         100         mV/ms           External Capacitance         All         lo         0         -         100         mV/ms           Output Current         All         lo         0         -         110         Aac           V(v=290% of Vo, set)         -         <	Nominal Output Voltage Set-point						
Over all operating input voltage, resistive load, and temperature conditions until end of life  Output Regulation   Line (V <sub>IN</sub> =V <sub>IN, min</sub> to V <sub>IN, max</sub> )   All	V <sub>IN</sub> =V <sub>IN, min</sub> , I <sub>O</sub> =I <sub>O, max</sub> , T <sub>A</sub> =25°C)	All	V <sub>O</sub> , set	11.76	12.0	12.24	V <sub>dc</sub>
temperature conditions until end of life)  Output Regulation  Line (Vm, m, m to Vm, max)  Load (lo=lo, min to Io, max)  Temperature (Tro=TA, min to TA, max)  All  Output Ripple and Noise on nominal output  (Vm, Nm, mo, Jo= 10, max, T,=TA, min to TA, max)  RMS (5Hz to 20MHz bandwidth)  All  Co  100  mV <sub>ms</sub> Rexternal Capacitance  All  Output Current  Output Current  Output Current Limit Inception (Hiccup Mode)  (Vo=90% of Vo, set)  Output Short-Circuit Current  (Vo≤250mV) (Hiccup Mode)  Efficiency  Vm VM, Nn, nom, Ta=25°C  Load Change from Io=50% to 75% or 25% to 50% of Io, max;  Peak Deviation  All  Vpk  All  Fix  All  All  All  All  All  All  All  A	Output Voltage						
Output Regulation         All         —         —         0.2         % V <sub>0, set</sub> Line (V <sub>m</sub> =V <sub>Mr, min</sub> to V <sub>Mr, max</sub> )         All         —         —         0.2         % V <sub>0, set</sub> Load (lo=lo, min to Io, max)         All         —         —         0.2         % V <sub>0, set</sub> Temperature (Tr <sub>cl</sub> =TA, min to TA, max)         All         —         —         1.0         % V <sub>0, set</sub> Output Ripple and Noise on nominal output (V <sub>Mr</sub> =V <sub>Mr, mon</sub> , Jo= Io, max, T <sub>x</sub> =TA, min to TA, max)         All         —         —         30         mV <sub>mrs</sub> RMS (5Hz to 20MHz bandwidth)         All         —         —         30         mV <sub>mrs</sub> RMS (5Hz to 20MHz bandwidth)         All         —         —         100         mV <sub>mrs</sub> External Capacitance         All         Lo         —         —         100         mV <sub>mrs</sub> Output Current         All         Io         0         —         10         Adc           Output Current Limit Inception (Hiccup Mode)         All         Io, lim         105         115         130         % Io           (Vo=90% of V <sub>0,set</sub> )         All         Io, lim         Io         93.5         \$         Arms	(Over all operating input voltage, resistive load, and	All	Vo	-3.0	_	+3.0	$\% V_{O, set}$
Line (V <sub>III</sub> =V <sub>IN, min</sub> to V <sub>IN, max</sub> )	·						
Load (lo=lo, min to 1o, max)							
Temperature (TreeF1, min to TA, max)	, , , , , , , , , , , , , , , , , , , ,			_	_	0.2	-,
Output Ripple and Noise on nominal output $(V_{IN}=V_{IN, nom, IO}=I_{O, max, T}, T_{A}=T_{A, min}$ to $T_{A, max})$ All $I_{O, Min}=I_{O, max, T}$ (SHz to 20MHz bandwidth) All $I_{O, Min}=I_{O, max, T}$ (SHz to 20MHz bandwidth) All $I_{O, Min}=I_{O, $				_	_	_	-,
(V <sub>IN</sub> =V <sub>IN, nom, IO= I<sub>O, max</sub>, T<sub>A</sub>=T<sub>A, min</sub> to T<sub>A, max</sub>)   All                                 </sub>		All		_		1.0	% V <sub>O, set</sub>
RMS (5Hz to 20MHz bandwidth)       All       —       —       30       mV <sub>rms</sub> Peak-to-Peak (5Hz to 20MHz bandwidth)       All       —       —       100       mV <sub>pk-pk</sub> External Capacitance       All       Co       100       —       2,000       µF         Output Current       All       Io       0       —       10       Adc         Output Current Limit Inception (Hiccup Mode)       All       Io, lim       105       115       130       % Io         Output Short-Circuit Current (Vo≤250mV) ( Hiccup Mode)       All       Io, s/c       —       3       5       A <sub>rms</sub> Efficiency       All       η       93.5       %         V <sub>IN</sub> = V <sub>IN, nom</sub> , T <sub>A</sub> =25°C       Io=Io, max, Vo= V <sub>O,set</sub> 370       kHz         Switching Frequency (Input ripple is ½ f <sub>sw</sub> )       All       f <sub>sw</sub> 370       kHz         Dynamic Load Response (dlo/dt=0.1A/µs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C)       All       V <sub>pk</sub> —       3       —       % Vo, set         Load Change from Io= 50% to 75% or 25% to 50% of Io, max;       All       V <sub>pk</sub> —       3       —       % Vo, set         Load Change from Io= 50% to 75% or 25% to 50% of Io, max (pk)       All       V <sub>pk</sub> <t< td=""><td></td><td></td><td></td><td></td><td></td><td></td><td></td></t<>							
Peak-to-Peak (5Hz to 20MHz bandwidth)         All         —         —         100         mV <sub>pk-pk</sub> External Capacitance         All         Co         100         —         2,000         μF           Output Current         All         Io         0         —         10         Adc           Output Current Limit Inception (Hiccup Mode )         All         Io, lim         105         115         130         % Io           (Vo = 90% of Vo, set)         All         Io, lim         105         115         130         % Io           Output Short-Circuit Current (Vo≤250mV) ( Hiccup Mode )         All         Io, s/c         —         3         5         Arms           Efficiency V <sub>IIN</sub> V <sub>IN, nom</sub> , Ta=25°C Io=Io, max, Vo= Vo, set         All         η         93.5         %           Switching Frequency (Input ripple is ½ fsw)         All         fsw         370         kHz           Dynamic Load Response (dIo/dt=0.1A/µs; V <sub>IN</sub> = V <sub>IN, nom</sub> , Ta=25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max; Peak Deviation         All         Vpk         —         3         —         % Vo, set           Settling Time (Vo<10% peak deviation) (dIo/dt=1A/µs; V <sub>IN</sub> = V <sub>IN, nom</sub> , Ta=25°C) Load Change from Io= 50% to 75% or 25% to 50% of         All         Ts         —         3							
External Capacitance  All  Co 100  Dutput Current  All  Io 0  T  10  Adc  Output Current Limit Inception (Hiccup Mode) (Vo= 90% of Vo, set)  Output Short-Circuit Current (Vo≤250mV) ( Hiccup Mode)  Efficiency VIN= VIN, nom, TA=25°C Io=Io, max, Vo= Vo, set  Switching Frequency (Input ripple is ½ fsw)  Dynamic Load Response (dIo/dt=0.1A/μs; VIN = VIN, nom; TA=25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max;  Peak Deviation  Settling Time (Vo<10% peak deviation) (dIo/dt=1A/μs; VIN = VIN, nom; TA=25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max;  Co 100  — 10  Adc  105  115  130  % Io  105  115  130  % Io  107  AIII  108  AIII  109  AIII  AIIII  AIIIII  AIIII  AIIII  AIIII  AIIIII  AIIII  AIIII  AIIII  AIIII  AIIIII  AIIIII  AIIII  AIIIII  AIIII  AIIII  AII	RMS (5Hz to 20MHz bandwidth)	All		_		30	mV <sub>rms</sub>
Output Current         All         Io         0         —         10         Adc           Output Current Limit Inception (Hiccup Mode) (Vo= 90% of Vo, set)         All         Io, lim         105         115         130         % Io           Output Short-Circuit Current (Vo≤250mV) (Hiccup Mode)         All         Io, s/c         —         3         5         A <sub>rms</sub> Efficiency V <sub>IN</sub> = V <sub>IN, nom</sub> , Ta=25°C Io=Io, max, Vo= Vo, set         All         η         93.5         %           Switching Frequency (Input ripple is ½ f <sub>sw</sub> )         All         f <sub>sw</sub> 370         kHz           Dynamic Load Response (dlo/dt=0.1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; Ta=25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max; Peak Deviation         All         V <sub>pk</sub> —         3         —         % Vo, set           Settling Time (Vo<10% peak deviation) (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; Ta=25°C) Load Change from Io= 50% to 75% or 25% to 50% of         All         t <sub>s</sub> —         3         —         % Vo, set	Peak-to-Peak (5Hz to 20MHz bandwidth)	All		_	_	100	$mV_{pk-pk}$
Output Current Limit Inception (Hiccup Mode )       All       Io, lim       105       115       130       % Io         Output Short-Circuit Current (Vo≤250mV) (Hiccup Mode )       All       Io, s/c       —       3       5       Arms         Efficiency V <sub>IN</sub> = V <sub>IN, nom</sub> , T <sub>A</sub> =25°C Io=Io, max, Vo= Vo, set       All       η       93.5       %         Switching Frequency (Input ripple is ½ fsw)       All       fsw       370       kHz         Dynamic Load Response (dlo/dt=0.1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max; Peak Deviation       All       V <sub>pk</sub> —       3       —       % Vo, set         Settling Time (Vo<10% peak deviation) (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max (dlo/dt=1A/μs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of Io, max (dlo/dt=1A/μs) Load Change from Io= 50% to 75% or 25% to 50% of	External Capacitance	All	Co	100	_	2,000	μF
(Vo= 90% of Vo, set)   Symbol   Symb	Output Current	All	lo	0	_	10	$A_{dc}$
Output Short-Circuit Current ( $V_0 \le 250 \text{mV}$ ) ( Hiccup Mode )  Efficiency	Output Current Limit Inception (Hiccup Mode )	All	I <sub>O, lim</sub>	105	115	130	% I。
	$(V_0 = 90\% \text{ of } V_{O, \text{ set}})$						
Efficiency $V_{IN} = V_{IN, nom, Ta} = 25^{\circ}C$ $I_{O=IO, max}, V_{O=VO, set}$ All $I_{O=IO, max} = V_{O=IO, max} = V_{O=IO$	Output Short-Circuit Current	All	la i		2	_	_
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	(Vo≤250mV) ( Hiccup Mode )	All	10, s/c		3	3	Arms
$I_{O=I_{O, max}, V_{O}=V_{O, set}}$ Switching Frequency (Input ripple is ½ $f_{sw}$ ) All $f_{sw}$ 370 kHz  Dynamic Load Response $(dI_{O}/dt=0.1A/\mu s; \ V_{IN}=V_{IN, nom}; T_{A}=25^{\circ}C)$ Load Change from Io= 50% to 75% or 25% to 50% of Io,max; Peak Deviation $Settling Time (Vo<10\% peak deviation)$ $(dI_{O}/dt=1A/\mu s; \ V_{IN}=V_{IN, nom}; T_{A}=25^{\circ}C)$ Load Change from Io= 50% to 75% or 25% to 50% of Io,max; $(dI_{O}/dt=1A/\mu s; \ V_{IN}=V_{IN, nom}; T_{A}=25^{\circ}C)$ Load Change from Io= 50% to 75% or 25% to 50% of	Efficiency	All	η		93.5		%
Switching Frequency (Input ripple is ½ $f_{sw}$ )  All $f_{sw}$ 370  kHz  Dynamic Load Response  (dIo/dt=0.1A/ $\mu$ s; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C)  Load Change from Io= 50% to 75% or 25% to 50% of Io,max;  Peak Deviation  Settling Time (Vo<10% peak deviation)  (dIo/dt=1A/ $\mu$ s; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C)  Load Change from Io= 50% to 75% or 25% to 50% of	V <sub>IN</sub> = V <sub>IN, nom</sub> , T <sub>A</sub> =25°C						
Dynamic Load Response (dlo/dt=0.1A/ $\mu$ s; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from lo= 50% to 75% or 25% to 50% of lo,max; Peak Deviation All V <sub>pk</sub> — 3 — % V <sub>o, set</sub> Settling Time (Vo<10% peak deviation) All t <sub>s</sub> — 200 — $\mu$ s (dlo/dt=1A/ $\mu$ s; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from lo= 50% to 75% or 25% to 50% of	$I_O=I_{O, max}$ , $V_O=V_{O, set}$						
	Switching Frequency (Input ripple is ½ f <sub>sw</sub> )	All	f <sub>sw</sub>		370		kHz
Load Change from lo= 50% to 75% or 25% to 50% of lo,max; Peak Deviation All $V_{pk}$ — 3 — % $V_{0,set}$ Settling Time (Vo<10% peak deviation) All $t_s$ — 200 — $\mu s$ (dlo/dt=1A/ $\mu s$ ; $V_{IN}$ = $V_{IN,nom}$ ; $T_A$ =25°C) Load Change from lo= 50% to 75% or 25% to 50% of	Dynamic Load Response						
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$(dIo/dt=0.1A/\mu s; V_{IN} = V_{IN, nom}; T_A=25^{\circ}C)$						
Peak Deviation All $V_{pk}$ — 3 — % $V_{0, set}$ Settling Time (Vo<10% peak deviation) All $t_s$ — 200 — $\mu s$ (dIo/dt=1A/ $\mu$ s; $V_{IN} = V_{IN, nom}$ ; $T_A$ =25°C) Load Change from Io= 50% to 75% or 25% to 50% of	Load Change from Io= 50% to 75% or 25% to 50% of						
Settling Time (Vo<10% peak deviation) All $t_s$ — 200 — $\mu s$ (dIo/dt=1A/ $\mu s$ ; $V_{IN}$ = $V_{IN, nom}$ ; $T_A$ =25°C) Load Change from Io= 50% to 75% or 25% to 50% of	lo,max;						
(dIo/dt=1A/µs; V <sub>IN</sub> = V <sub>IN, nom</sub> ; T <sub>A</sub> =25°C) Load Change from Io= 50% to 75% or 25% to 50% of	Peak Deviation	All	$V_{pk}$		3		% V <sub>O, set</sub>
Load Change from Io= 50% to 75% or 25% to 50% of	Settling Time (Vo<10% peak deviation)	All	ts	_	200	_	μs
Load Change from Io= 50% to 75% or 25% to 50% of	(dlo/dt=1A/ $\mu$ s; $V_{IN} = V_{IN, nom}$ ; $T_A=25$ °C)						
10,max;	lo,max;						
Peak Deviation All V <sub>pk</sub> — 5 — % V <sub>O, set</sub>	Peak Deviation	All	$V_{pk}$	_	5	_	% V <sub>O, set</sub>
Settling Time (Vo<10% peak deviation)  All  t <sub>s</sub> 200  μs	Settling Time (Vo<10% peak deviation)	All	,	_	200	_	

### **Isolation Specifications**

Parameter	Device	Symbol	Min	Тур	Max	Unit
Isolation Capacitance	All	C <sub>iso</sub>		1000		pF
Isolation Resistance	All	R <sub>iso</sub>	10		_	МΩ
I/O Isolation Voltage (100% factory Hi-pot tested)	All	All	_	_	2250	$V_{dc}$

### **General Specifications**

Parameter	Device	Symbol	Min	Тур	Max	Unit
Calculated Reliability based upon Telcordia SR-332	All	FIT		323.4		10 <sup>9</sup> /Hours
Issue 2: Method I Case 3 (Io=80%Io, max, T <sub>A</sub> =40°C, airflow = 200 lfm, 90% confidence)	All	MTBF		3,092,530		Hours
Weight (Open Frame)	All		_	19 (0.67)	_	g (oz.)
Weight (with Heatplate)	All		_	32 (1.13)	_	g (oz.)

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36–75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Feature Specifications**

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Device	Symbol	Min	Тур	Max	Unit
Remote On/Off Signal Interface						
$(V_{IN} {=} V_{IN,min}$ to $V_{IN,max}$ ; open collector or equivalent,						
Signal referenced to V <sub>IN-</sub> terminal)						
Negative Logic: device code suffix "1"						
Logic Low = module On, Logic High = module Off						
Positive Logic: No device code suffix required						
Logic Low = module Off, Logic High = module On						
Logic Low - Remote On/Off Current	All	I <sub>on/off</sub>	_	_	1.0	mA
Logic Low - On/Off Voltage	All	$V_{on/off}$	-0.7	_	1.0	$V_{dc}$
Logic High Voltage – (Typ = Open Collector)	All	V <sub>on/off</sub>	2.0		5.0	$V_{dc}$
Logic High maximum allowable leakage current	All	I <sub>on/off</sub>	_	_	10	μΑ
Turn-On Delay¹ and Rise Times						
$(I_0=I_{0, max}, V_{IN}=V_{IN, nom}, T_A = 25  {}^{\circ}C)$						
Case 1: On/Off input is set to Logic Low (Module						
ON) and then input power is applied (T <sub>delay</sub> from	All	$T_{delay}$	_	25	30	msec
instant at which $V_{IN} = V_{IN, min}$ until $V_O = 10\%$ of $V_{O,set}$ )  Case 2: Input power is applied for at least 1 second						
and then the On/Off input is set from OFF to ON (T <sub>delay</sub> from	All	$T_{delav}$	_	12	20	msec
instant $V_{on/off}$ toggles until $V_0 = 10\%$ of $V_{O, set}$ ).		Gulay				
Output voltage Rise time (time for Vo to rise from 10%	All	T <sub>rise</sub>	_	10	15	msec
of V <sub>o,set</sub> to 90% of V <sub>o,set</sub> )	All	l rise		10	13	IIISEC
Output voltage overshoot – Startup	All			_	3	% V <sub>O, set</sub>
$I_0$ = $I_{O, max}$ ; $V_{IN}$ = $V_{IN, min}$ to $V_{IN, max}$ , $T_A$ = 25 °C	7 111					70 V O, Set
Remote Sense Range	All	V <sub>SENSE</sub>			10	% V <sub>O, set</sub>
(Max voltage drop is 0.5V)						
Output Voltage Adjustment Range <sup>2</sup>	All		80		110	% V <sub>O, set</sub>
Output Overvoltage Protection	All	V <sub>O, limit</sub>	13.8	_	16.5	$V_{dc}$
Input Undervoltage Lockout	All	$V_{\text{UVLO}}$				
Turn-on Threshold			30	34.5	36	$V_{dc}$
Turn-off Threshold			30	32.5	_	$V_{dc}$
Hysterisis			1.5	2.0	_	$V_{dc}$
Input Overvoltage Lockout	All	V <sub>OVLO</sub>				
Turn-off Threshold			_	80	83	$V_{dc}$
Turn-on Threshold			75	78	_	$V_{dc}$
Hysterisis			1	2	_	$V_{dc}$

#### Notes:

<sup>1.</sup> The module has an adaptable extended Turn-On Delay interval, T<sub>delay</sub>, of 4 seconds. The extended T<sub>delay</sub> will occur when the module restarts following either: 1) the rapid cycling of Vin from normal levels to less than the Input Undervoltage Lockout (which causes module shutdown), and then back to normal; or 2) toggling the on/off signal from on to off and back to on without removing the input voltage. The normal Turn-On Delay interval, T<sub>delay</sub>, will occur whenever a module restarts with input voltage removed from the module for the preceding 1 second.

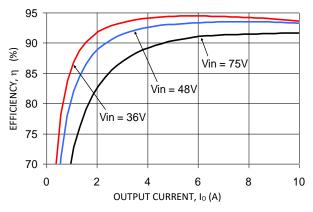
<sup>2.</sup> Maximum trim up possible only for Vin>40V.

# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Characteristic Curves**

The following figures provide typical characteristics for the EVW010A0B (12V, 10A) at 25°C. The figures are identical for either positive or negative remote On/Off logic.

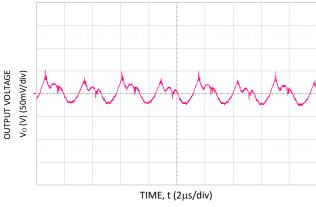


OUTPUT VOLTAGE OUTPUT CURRENT
Vo (V) (200mV/div) Io(A) (2A/div)

TIME' t (100ħ²/qiv)

Figure 1. Converter Efficiency versus Output Current.

Figure 4. Transient Response to 1.0A/ $\mu$ S Dynamic Load Change from 50% to 75% to 50% of full load (V<sub>IN</sub> = V<sub>IN,NOM</sub>).



On/Off voltage
Vo (v) (2v/div)

Apply 2 (v) (2v/div)

Apply 3 (v) (2v/div)

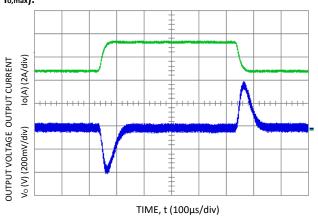
Apply 4 (v) (2v/div)

Apply 5 (v) (2v/div)

TIME' f (2ws/qiv)

Figure 2. Typical output ripple and noise ( $V_{IN}$  =  $V_{IN,NOM}$ ,  $I_{o}$  =  $I_{o,max}$ ).

Figure 5. Typical Start-up Using Remote On/Off, negative logic version shown ( $V_{IN} = V_{IN,NOM}$ ,  $I_0 = I_{O,max}$ ).



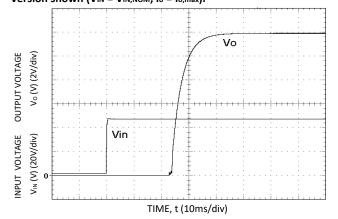


Figure 3. Transient Response to  $0.1A/\mu S$  Dynamic Load Change from 50% to 75% to 50% of full load ( $V_{IN} = V_{IN,NOM}$ ).

Figure 6. Typical Start-up Using Input Voltage ( $V_{IN} = V_{IN,NOM}$ ,  $I_{O} = I_{O,max}$ ).

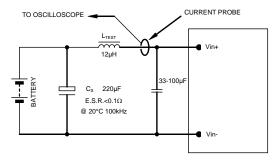
Data Sheet GE

# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules 36–75Vdc Input; 12.0Vdc Output; 10A Output Current

# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

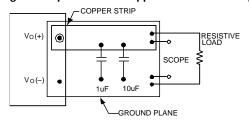
36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Test Configurations**



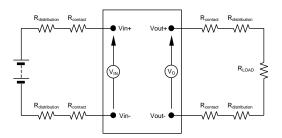
NOTE: Measure input reflected ripple current with a simulated source inductance ( $L_{\text{TEsT}}$ ) of 12µH. Capacitor  $C_{\text{S}}$  offsets possible battery impedance. Measure current as shown above.

Figure 7. Input Reflected Ripple Current Test Setup.



NOTE: All voltage measurements to be taken at the module terminals, as shown above. If sockets are used then Kelvin connections are required at the module terminals to avoid measurement errors due to socket contact resistance.

Figure 8. Output Ripple and Noise Test Setup.



NOTE: All voltage measurements to be taken at the module terminals, as shown above. If sockets are used then Kelvin connections are required at the module terminals to avoid measurement errors due to socket contact resistance.

Figure 9. Output Voltage and Efficiency Test Setup.

Efficiency 
$$\eta = \frac{V_0. I_0}{V_{IN} I_{IN}} \times 100 \%$$

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Design Considerations**

#### **Input Filtering**

The power module should be connected to a low ac-impedance source. Highly inductive source impedance can affect the stability of the power module. For the test configuration in Figure 7 a 33-100 $\mu$ F electrolytic capacitor (ESR<0.1 $\Omega$  at 100kHz), mounted close to the power module helps ensure the stability of the unit. Consult the factory for further application guidelines.

### **Safety Considerations**

For safety agency approval the power module must be installed in compliance with the spacing and separation requirements of the end-use safety agency standards, i.e., UL ANSI/UL 62368-1 and CAN/CSA C22.2 No. 62368-1 Recognized, DIN VDE 0868-1/A11:2017 (EN62368-1:2014/A11:2017)

If the input source is non-SELV (ELV or a hazardous voltage greater than 60 Vdc and less than or equal to 75Vdc), for the module's output to be considered as meeting the requirements for safety extra-low voltage (SELV) or ES1, all of the following must be true:

- The input source is to be provided with reinforced insulation from any other hazardous voltages, including the ac mains.
- One V<sub>IN</sub> pin and one V<sub>OUT</sub> pin are to be grounded, or both the input and output pins are to be kept floating.
- The input pins of the module are not operator accessible.
- Another SELV or ES1 reliability test is conducted on the whole system (combination of supply source and subject module), as required by the safety agencies, to verify that under a single fault, hazardous voltages do not appear at the module's output.

**Note:** Do not ground either of the input pins of the module without grounding one of the output pins. This may allow a non-SELV/ES1 voltage to appear between the output pins and ground.

The power module has safety extra-low voltage (SELV) or ES1 outputs when all inputs are SELV or ES1.

All flammable materials used in the manufacturing of these modules are rated 94V-0, or tested to the in-situ needle flame test for reduced thickness.

For input voltages exceeding –60 Vdc but less than or equal to –75 Vdc, these converters have been evaluated to the applicable requirements of BASIC INSULATION between secondary DC MAINS DISTRIBUTION input (classified as TNV-2 in Europe) and unearthed SELV outputs.

The input to these units is to be provided with a maximum 8 A time-delay fuse in the ungrounded lead.

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Feature Description**

### Remote On/Off

Two remote on/off options are available. Positive logic turns the module on during a logic high voltage on the ON/OFF pin, and off during a logic low. Negative logic remote On/Off, device code suffix "1", turns the module off during a logic high and on during a logic low.

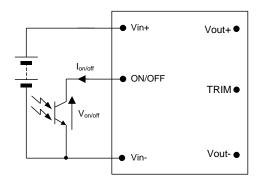


Figure 10. Remote On/Off Implementation.

To turn the power module on and off, the user must supply a switch (open collector or equivalent) to control the voltage  $(V_{on/off})$  between the ON/OFF terminal and the  $V_{IN}(-)$  terminal (see Figure 10). Logic low is  $0V \le V_{on/off} \le 1.0V$ . The maximum  $I_{on/off}$  during a logic low is 1mA, the switch should be maintain a logic low level whilst sinking this current.

During a logic high, the typical maximum  $V_{\text{on/off}}$  generated by the module is 5V, and the maximum allowable leakage current at  $V_{\text{on/off}}$  = 5V is 1 $\mu$ A.

If not using the remote on/off feature:

For positive logic, leave the ON/OFF pin open.

For negative logic, short the ON/OFF pin to V<sub>IN</sub>(-).

### **Remote Sense**

Remote sense minimizes the effects of distribution losses by regulating the voltage at the remote-sense connections (See Figure 11). The voltage between the remote-sense pins and the output terminals must not exceed the output voltage sense range given in the Feature Specifications table:

$$[V_0(+) - V_0(-)] - [SENSE(+) - SENSE(-)] \le 0.5 \text{ V}$$

Although the output voltage can be increased by both the remote sense and by the trim, the maximum increase for the output voltage is not the sum of both. The maximum increase is the larger of either the remote sense or the trim.

The amount of power delivered by the module is defined as the voltage at the output terminals multiplied by the output current. When using remote sense and trim, the output voltage of the module can be increased, which at the same output current would increase the power output of the module. Care should be taken to ensure that the maximum output power of the module remains at or below the maximum rated power (Maximum rated power = Vo,set x Io,max).

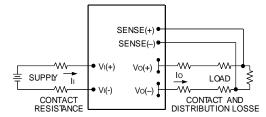


Figure 11. Circuit Configuration for remote sense.

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Input Undervoltage Lockout**

At input voltages below the input undervoltage lockout limit, the module operation is disabled. The module will only begin to operate once the input voltage is raised above the undervoltage lockout turn-on threshold,  $V_{UV/ON}$ .

Once operating, the module will continue to operate until the input voltage is taken below the undervoltage turn-off threshold,  $V_{\text{UV/OFF}}$ .

#### **Overtemperature Protection**

To provide protection under certain fault conditions, the unit is equipped with a thermal shutdown circuit. The unit will shutdown if the thermal reference point Tref (Figure 13), exceeds 150°C (typical), but the thermal shutdown is not intended as a guarantee that the unit will survive temperatures beyond its rating. The module can be restarted by cycling the dc input power for at least one second or by toggling the remote on/off signal for at least one second. If the auto-restart option (4) is ordered, the module will automatically restart upon cool-down to a safe temperature.

### **Output Overvoltage Protection**

The output over voltage protection scheme of the modules has an independent over voltage loop to prevent single point of failure. This protection feature latches in the event of over voltage across the output. Cycling the on/off pin or input voltage resets the latching protection feature. If the auto-restart option (4) is ordered, the module will automatically restart upon an internally programmed time elapsing.

#### **Overcurrent Protection**

To provide protection in a fault (output overload) condition, the unit is equipped with internal current-limiting circuitry and can endure current

limiting continuously. At the point of current-limit

inception, the unit enters hiccup mode. If the unit is

not configured with auto-restart, then it will latch off

following the over current condition. The module can be restarted by cycling the dc input power for at least one second or by toggling the remote on/off signal for at least one second. If the unit is configured with the auto-restart option (4), it will remain in the hiccup mode as long as the overcurrent condition exists; it operates normally, once the output current is brought back into its specified range. The average output current during hiccup is 10% I<sub>O, max</sub>.

#### **Output Voltage Programming**

Trimming allows the output voltage set point to be increased or decreased, this is accomplished by connecting an external resistor between the TRIM pin and either the  $V_0(+)$  pin or the  $V_0(-)$  pin.

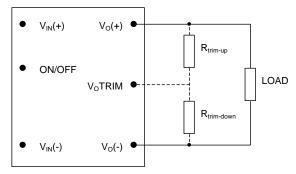


Figure 12. Circuit Configuration to Trim Output Voltage.

Connecting an external resistor (R<sub>trim-down</sub>) between the TRIM pin and the Vo(-) (or Sense(-)) pin decreases the output voltage set point. To maintain set point accuracy, the trim resistor tolerance should be ±1.0%.

The following equation determines the required external resistor value to obtain a percentage output voltage change of  $\Delta\%$ 

$$R_{trim-down} = \left[\frac{511}{\Delta\%} - 10.22\right] \text{K}\Omega$$

Where 
$$\Delta\% = \left(\frac{V_{o,set} - V_{desired}}{V_{o,set}}\right) \times 100$$

For example, to trim-down the output voltage of the module by 8% to 11.04V, Rtrim-down is calculated as follows:

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

$$\Delta\% = 8$$

$$R_{trim-down} = \left[\frac{511}{8} - 10.22\right] \text{K}\Omega$$

$$R_{trim-down} = 53.655 \text{K}\Omega$$

Connecting an external resistor ( $R_{trim-up}$ ) between the TRIM pin and the  $V_0(+)$  (or Sense (+)) pin increases the output voltage set point. The following equations determine the required external resistor value to obtain a percentage output voltage change of  $\Delta$ %:

$$R_{trim-up} = \Bigg[\frac{5.11 \times V_{o,set} \times (100 + \Delta\%)}{1.225 \times \Delta\%} - \frac{511}{\Delta\%} - 10.22\Bigg] \text{K}\Omega$$
 Where 
$$\Delta\% = \Bigg(\frac{V_{desired} - V_{o,set}}{V_{o,set}}\Bigg) \times 100$$

For example, to trim-up the output voltage of the module by 5% to 12.6V, R<sub>trim-up</sub> is calculated is as follows:

$$R_{trim-up} = \left[ \frac{5.11 \times 12.0 \times (100 + 5)}{1.225 \times 5} - \frac{511}{5} - 10.22 \right] K\Omega R_{trim-up} = 938.8 K\Omega$$

The voltage between the Vo(+) and Vo(-) terminals must not exceed the minimum output overvoltage protection value shown in the Feature Specifications table. This limit includes any increase in voltage due to remote-sense compensation and output voltage set-point adjustment trim.

Although the output voltage can be increased by both the remote sense and by the trim, the maximum increase for the output voltage is not the sum of both. The maximum increase is the larger of either the remote sense or the trim. The amount of power delivered by the module is defined as the voltage at the output terminals multiplied by the output current. When using remote sense and trim, the output voltage of the module can be increased, which at the same output current would increase the power output of the module. Care should be taken to ensure that the maximum output power of the module remains at or below the maximum rated power (Maximum rated power = V<sub>O,set</sub> x I<sub>O,max</sub>).

### **Thermal Considerations**

The power modules operate in a variety of thermal environments; however, sufficient cooling should be provided to help ensure reliable operation.

Considerations include ambient temperature, airflow, module power dissipation, and the need for increased reliability. A reduction in the operating temperature of the module will result in an increase in reliability. The thermal data presented here is based on physical measurements taken in a wind tunnel.

The thermal reference point, T<sub>ref</sub> used in the specifications for open frame modules is shown in Figure 13. For reliable operation this temperature should not exceed 122°C.

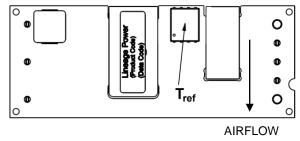


Figure 13. T<sub>ref</sub> Temperature Measurement Location for open Frame Module.

The thermal reference point, T<sub>ref</sub> used in the specifications for modules with heat plates (–H) is shown in Figure 14. For reliable operation this temperature should not exceed 114°C.

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### Thermal Considerations (continued)

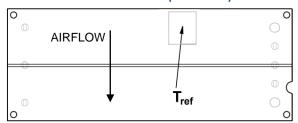


Figure 14. T<sub>ref</sub> Temperature Measurement Location for Heat plate Module.

#### **Heat Transfer via Convection**

Increased airflow over the module enhances the heat transfer via convection. Derating curves showing the

maximum output current that can be delivered by the open frame module versus local ambient temperature ( $T_A$ ) for natural convection and up to 3m/s (600 ft./min) forced airflow are shown in Figure 15.

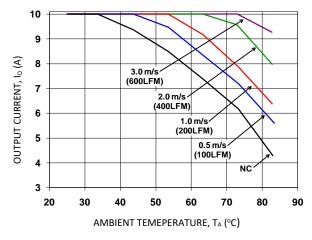


Figure 15. Output Current Derating for the Open Frame Module; Airflow in the Transverse Direction from Vout(+) to Vout(-); Vin =48V.

For additional power, the module is available with an optional heatplate (-H), that allows for the use of heatsinks to improve the thermal derating. Derating curves showing the maximum output current that can be delivered by the heatplate module with different heatsink heights versus local ambient temperature (TA) for natural convection and up to 3m/s (600 ft./min) forced airflow are shown in Figures 16 -19.

# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

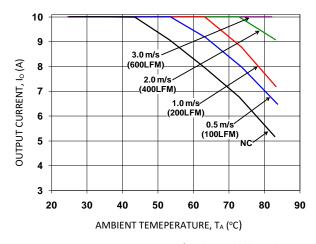


Figure 16. Output Current Derating for the Module with Heatplate; Airflow in the Transverse Direction from Vout(+) to Vout(-); Vin =48V.

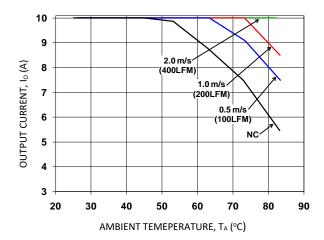


Figure 17. Output Current Derating for the Module with Heatplate and 0.25 in. heatsink; Airflow in the Transverse Direction from Vout(+) to Vout(-); Vin =48V.

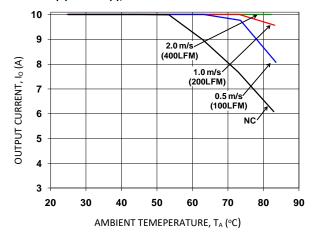


Figure 18. Output Current Derating for the Module with Heatplate and 0.5 in. heatsink; Airflow in the Transverse Direction from Vout(+) to Vout(-); Vin =48V.

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### Thermal Considerations (continued)

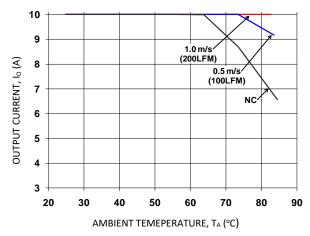


Figure 19. Output Current Derating for the Module with Heatplate and 1.0 in. heatsink; Airflow in the Transverse Direction from Vout(+) to Vout(-); Vin =48V.

Please refer to the Application Note "Thermal Characterization Process For Open-Frame Board-Mounted Power Modules" for a detailed discussion of thermal aspects including maximum device temperatures.

### **Through-Hole Soldering Information**

The RoHS-compliant (Z codes) through-hole products use the SAC (Sn/Ag/Cu) Pb-free solder and RoHS-compliant components. The RoHS-compliant with lead solder exemption (non-Z codes) through-hole products use Sn/Pb solder and RoHS-compliant components. Both non-Z and Z codes are designed to be processed through single or dual wave soldering machines. The pins have an RoHS-compliant finish that is compatible with both Pb and Pb-free wave soldering processes. A maximum preheat rate of 3°C/s is suggested. The wave preheat process should be such that the temperature of the power module board is kept below 210°C. For Pb solder, the recommended pot temperature is 260°C, while the Pb-free solder pot is 270°C max. Not all RoHS-compliant through-hole products can be processed with paste-through-hole Pb or Pb-free reflow process. If additional information is needed, please consult with your GE representative for more details.

#### **Surface Mount Information**

### **Pick and Place**

The EVW010A0B modules use an open frame construction and are designed for a fully automated assembly process. The modules are fitted with a label designed to provide a large surface area for pick and place operations. The label meets all the requirements for surface mount processing, as well as safety standards, and is able to withstand reflow temperatures of up to 300°C. The label also carries product information such as product code, serial number and the location of manufacture.

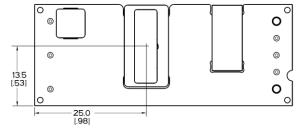


Figure 20. Pick and Place Location.

#### **Nozzle Recommendations**

The module weight has been kept to a minimum by using open frame construction. Even so, these modules have a relatively large mass when compared to conventional SMT components. Variables such as nozzle size, tip style, vacuum pressure and placement speed should be considered to optimize this process. The minimum recommended nozzle diameter for reliable operation is 6mm. The maximum nozzle outer diameter, which will safely fit within the allowable component spacing, is 9 mm.

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

Oblong or oval nozzles up to 11 x 9 mm may also be used within the space available.

#### **Reflow Soldering Information**

The surface mountable modules in the EVW family use our newest SMT technology called "Column Pin" (CP) connectors. Figure 21 shows the new CP connector before and after reflow soldering onto the end-board assembly.

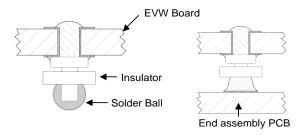


Figure 21. Column Pin Connector Before and After Reflow Soldering.

The CP is constructed from a solid copper pin with an integral solder ball attached, which is composed of tin/lead (Sn/Pb) solder for non-Z codes, or Sn/Ag/Cu (SAC) solder for –Z codes. The CP connector design is able to compensate for large amounts of co-planarity and still ensure a reliable SMT solder joint. Typically, the eutectic solder melts at 183°C (Sn/Pb solder) or 217-218 °C (SAC solder), wets the land, and subsequently wicks the device connection. Sufficient time must be allowed to fuse the plating on the connection to ensure a reliable solder joint. There are several types of SMT reflow technologies currently used in the industry. These surface mount power modules can be reliably soldered using natural forced convection, IR (radiant infrared), or a combination of convection/IR.

The following instructions must be observed when SMT soldering these units. Failure to observe these instructions may result in the failure of or cause damage to the modules, and can adversely affect long-term reliability.

### **Tin Lead Soldering**

The recommended linear reflow profile using Sn/Pb solder is shown in Figure 22 and 23. For reliable soldering the solder reflow profile should be established by accurately measuring the modules CP connector temperatures.

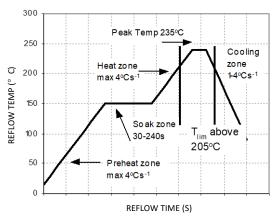


Figure 22. Recommended Reflow Profile for Tin/Lead (Sn/Pb) process

#### **Lead Free Soldering**

The –Z version of the EVW010A0B modules are lead-free (Pb-free) and RoHS compliant and are both forward and backward compatible in a Pb-free and a SnPb soldering process. Failure to observe the instructions below may result in the failure of or cause damage to the modules and can adversely affect long-term reliability.

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

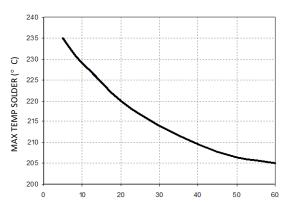


Figure 23. Time Limit, T<sub>lim</sub>, Curve Above 205°C for Tin/Lead (Sn/Pb) process

#### **Pb-free Reflow Profile**

Power Systems will comply with J-STD-020 Rev. C (Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices) for both Pb-free solder profiles and MSL classification procedures. This standard provides a recommended forced-air-convection reflow profile based on the volume and thickness of the package (table 4-2). The suggested Pb-free solder paste is Sn/Ag/Cu (SAC). The recommended linear reflow profile using Sn/Ag/Cu solder is shown in Fig. 24.

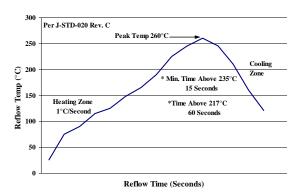


Figure 24. Recommended linear reflow profile using Sn/Ag/Cu solder

### **MSL Rating**

The EVW010A0B modules have a MSL rating of 2A.

### **Storage and Handling**

The recommended storage environment and handling procedures for moisture-sensitive surface mount packages is detailed in J-STD-033 Rev. A (Handling, Packing, Shipping and Use of Moisture/Reflow Sensitive Surface Mount Devices). Moisture barrier bags (MBB) with desiccant are required for MSL ratings of 2 or greater. These sealed packages should not be broken until time of use. Once the original package is broken, the floor life of the product at conditions of  $\leq 30^{\circ}$ C and 60% relative humidity varies according to the MSL rating (see J-STD-033A). The shelf life for dry packed SMT packages will be a minimum of 12 months from the bag seal date, when stored at the following conditions:  $<40^{\circ}$ C, <90% relative humidity.

### **Post Solder Cleaning and Drying Considerations**

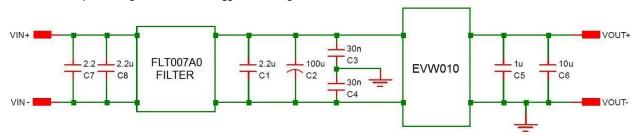
Post solder cleaning is usually the final circuit-board assembly process prior to electrical board testing. The result of inadequate cleaning and drying can affect both the reliability of a power module and the testability of the finished circuit-board assembly. For guidance on appropriate soldering, cleaning and drying procedures, refer to GE *Board Mounted Power Modules: Soldering and Cleaning* Application Note (AN04-001).

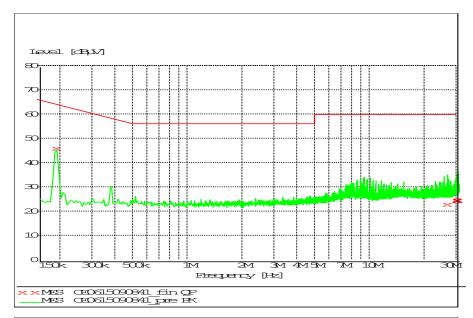
# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### **EMC Considerations**

The circuit and plots in Figure 25 shows a suggested configuration to meet the conducted emission limits of EN55032 Class B.





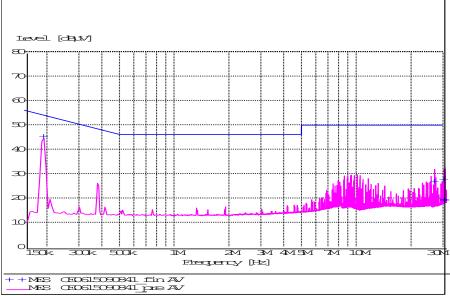


Figure 25. EMC Considerations

For further information on designing for EMC compliance, please refer to the FLT007A0 data sheet (DS05-028).

### EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

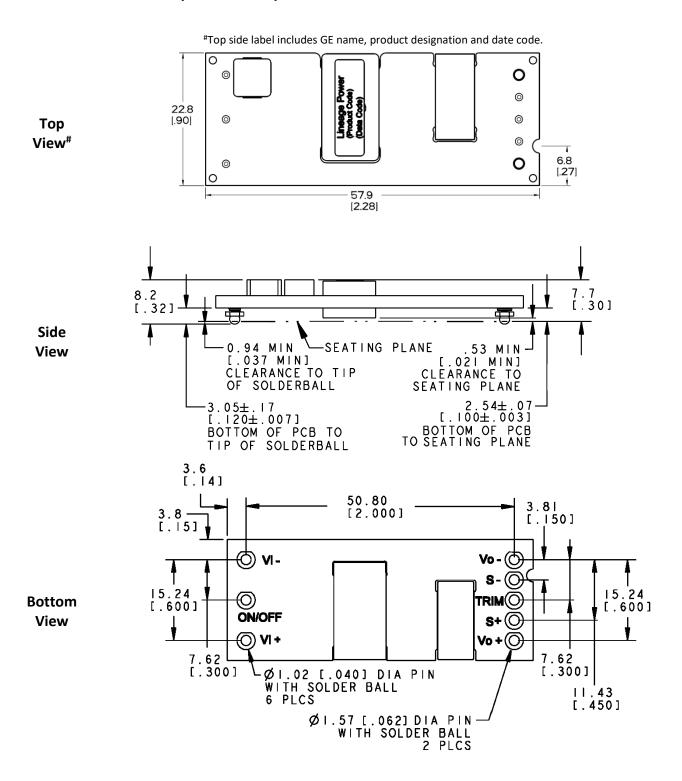
36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Mechanical Outline for Surface Mount Module**

Dimensions are in millimeters and [inches].

Tolerances: x.x mm  $\pm$  0.5 mm [x.xx in.  $\pm$  0.02 in.] (Unless otherwise indicated)

x.xx mm  $\pm$  0.25 mm [x.xxx in  $\pm$  0.010 in.]



# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

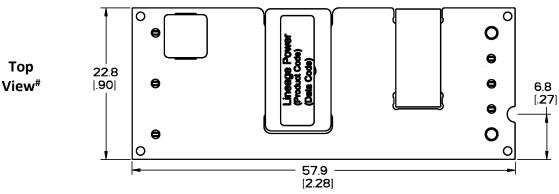
36-75Vdc Input; 12.0Vdc Output; 10A Output Current

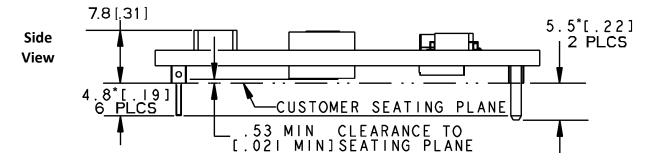
### **Mechanical Outline for Through-Hole Module**

Dimensions are in millimeters and [inches].

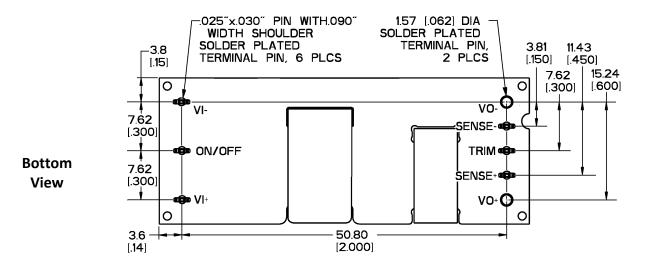
Tolerances: x.x mm  $\pm$  0.5 mm [x.xx in.  $\pm$  0.02 in.] (Unless otherwise indicated) x.xx mm  $\pm$  0.25 mm [x.xxx in  $\pm$  0.010 in.]

#Top side label includes GE name, product designation and date code.





\* For optional pin lengths, see Table 2 Device Options and Coding Scheme



Data Sheet GE

# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules 36–75Vdc Input; 12.0Vdc Output; 10A Output Current

## EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

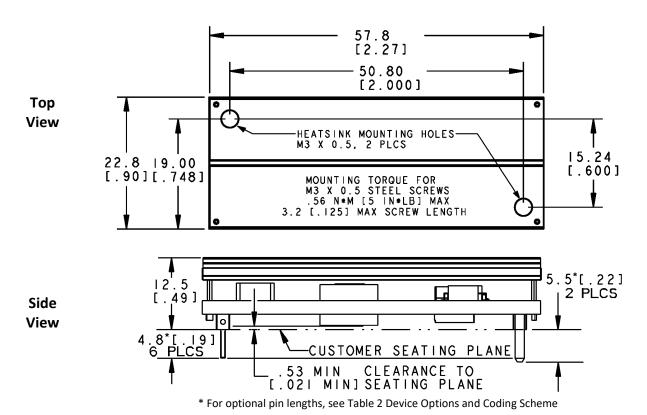
36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### Mechanical Outline for Through-Hole Module with Heat Plate (-H)

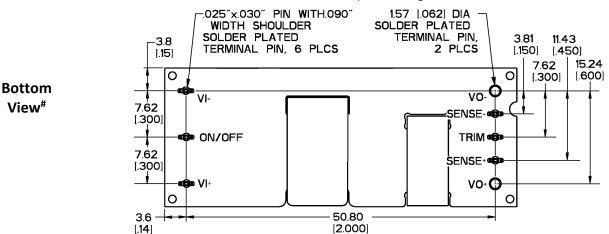
Dimensions are in millimeters and [inches].

Tolerances: x.x mm  $\pm$  0.5 mm [x.xx in.  $\pm$  0.02 in.] (Unless otherwise indicated)

x.xx mm  $\pm$  0.25 mm [x.xxx in  $\pm$  0.010 in.]



# Bottom side label includes GE name, product designation and date code.



# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

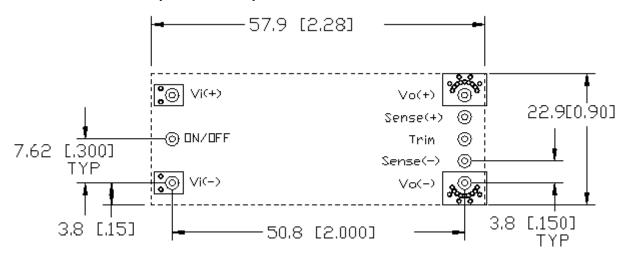
36-75Vdc Input; 12.0Vdc Output; 10A Output Current

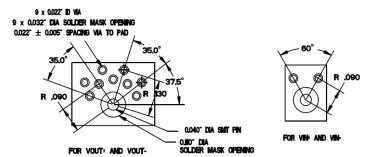
### **Recommended Pad Layout**

Dimensions are in millimeters and [inches].

Tolerances: x.x mm  $\pm$  0.5 mm [x.xx in.  $\pm$  0.02 in.] (Unless otherwise indicated)

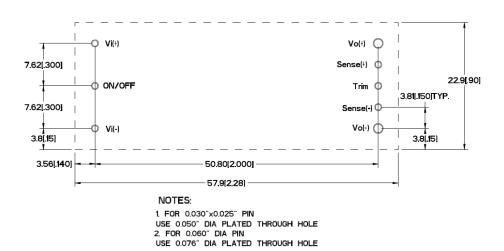
x.xx mm  $\pm$  0.25 mm [x.xxx in  $\pm$  0.010 in.]





### **SMT Recommended Pad Layout (Component Side View)**

Component Side View



### TH Recommended Pad Layout (Component Side View)

# EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36–75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Packaging Details**

The surface mount versions of the EVW surface mount modules (suffix -S) are supplied as standard in the plastic tray shown in Figure 26. The tray has external dimensions of 135.1mm (W) x 321.8mm (L) x 12.42mm (H) or 5.319in (W) x 12.669in (L) x 0..489in (H).

### **Tray Specification**

Material Antistatic coated PVC

 $\label{eq:max_surface} \begin{array}{ll} \text{Max surface resistivity} & 10^{12} \Omega/\text{sq} \\ \text{Color} & \text{Clear} \end{array}$ 

Capacity 12 power modules Min order quantity 48 pcs (1 box of 4 full trays)

Each tray contains a total of 12 power modules. The trays are self-stacking and each shipping box will contain 4 full trays plus one empty hold down tray giving a total number of 48 power modules.

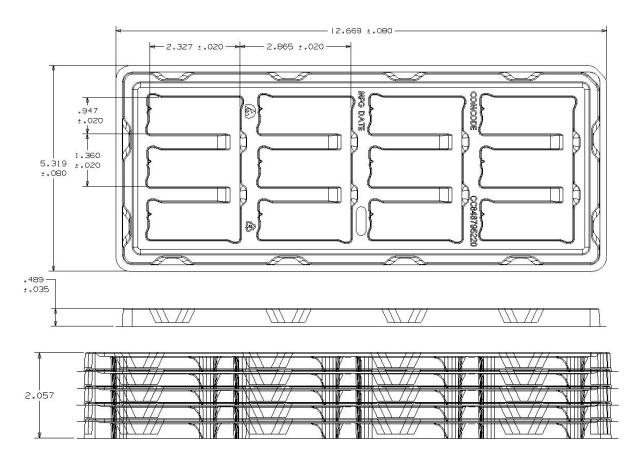


Figure 26. Surface Mount Packaging Tray.

## EVW010A0B Series (Eighth-Brick) DC-DC Power Modules

36-75Vdc Input; 12.0Vdc Output; 10A Output Current

### **Ordering Information**

Please contact your GE Sales Representative for pricing, availability and optional features.

**Table 1. Device Codes** 

Product Codes	Input Voltage	Output Voltage	Output Current	On/Off Logic	Connector Type	Comcodes
EVW010A0B41Z	48V (36-75Vdc)	12V	10A	Negative	Through hole	CC109143203
EVW010A0B64Z	48V (36-75Vdc)	12V	10A	Positive	Through hole	CC109156015
EVW010A0B641Z	48V (36-75Vdc)	12V	10A	Negative	Through hole	CC109158473
EVW010A0B41-HZ	48V (36-75Vdc)	12V	10A	Negative	Through hole	CC109152781
EVW010A0B41-SZ	48V (36-75Vdc)	12V	10A	Negative	Surface mount	CC109153516

Table 2. Device Options and Coding Scheme

		Characteristic	Character and Position	Definition			
		Form Factor	E	E = Eighth Brick			
1	gs	Family Designator	V				
ŀ	katın	Input Voltage	W	W = Wide Input Voltage Range, 36V -75V			
å	20	Output Current	010A0	010A0 = 010.0 Amps Rated Output Current			
		Output Voltage	В	B = 12.0 Vout Nominal			
				Omit = No Pin Trim			
		Pin Length	6	6 = Pin Length: 3.68 mm ± 0.25mm , (0.145 in. ± 0.010 in.)			
			8	8 = Pin Length: 2.79 mm ± 0.25mm, (0.110 in. ± 0.010 in.)			
		Action following		Omit = Latching Mode			
		Protective Shutdown	4	4 = Auto-restart following shutdown (Overcurrent/Overvoltage)			
	S	On /Off logic		Omit = Positive Logic			
	ıons	On/Off logic	1	1 = Negative Logic			
	Jpt		-				
	٦	Customer Specific	XY	XY = Customer Specific Modified Code, Omit for Standard Code			
				Omit = Standard open Frame Module			
		Mechanical Features	н	H = Heat plate (not available with –S option)			
			S	S = Surface mount connections			
		RoHS		Omit = RoHS 5/6, Lead Based Solder Used			
	KUNS		Z	Z = RoHS 6/6 Compliant, Lead free			

## **Contact Us**

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